innodisk

Total Solution For Industrial Flash Storage

M.2 (P80)

3ME2 Series

Customer: _____

Customer Part Number: _____

Innodisk Part Number: _____

Innodisk Model Name: _____

Date: _____

Innodisk Approver	Customer Approver

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Revision History

Revision	Description	Date
Preliminary 1.0	First release	Jun., 2018
Rev 1.0	Official released	Dec. 2018

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1. Product Overview

1.1 Introduction of Innodisk M.2 (P80) 3ME2

Innodisk M.2 (P80) 3ME2 is an NVM Express DRAM-less SSD designed as the standard M.2 form factor with PCIe interface and MLC NAND Flash. M.2 (P80)3ME2 supports PCIe Gen III x2, and it is compliant with NVM 1.3 providing excellent performance. Moreover, it adopts MLC NAND Flash providing high endurance and reliability. With sophisticated error detection and correction (ECC) functions, the module can ensure full End-to-end Data Path Protection that secures the data transmission between host system and NAND Flash.

Innodisk M.2 (P80) 3ME2 is integrated with Marvell controller which provide both low power consumption and efficient heat dissipation, making the SSD optimal for space-constrained IPCs and server boot-up applications.

1.2 Product View and Models

Innodisk M.2 (P80) 3ME2 is available in follow capacities within MLC flash ICs.

M.2 (P80) 3ME2 32GB

M.2 (P80) 3ME2 64GB

M.2 (P80) 3ME2 128GB

M.2 (P80) 3ME2 256GB

M.2 (P80) 3ME2 512GB

Figure 1: Innodisk M.2 (P80) 3ME2 (type 2280)

1.3 PCIe Interface

Innodisk M.2 (P80) 3ME2 supports PCIe Gen III interface and compliant with NVMe 1.3. M.2 (P80) 3ME2 can work under PCIe Gen 1, Gen 2 and Gen 3.

Most of operating system includes NVMe in-box driver now. For more information about the driver support in each OS, please visit http://nvmexpress.org/resources/drivers.

2. Product Specifications

2.1 Capacity and Device Parameters

M.2 (P80) 3ME2 device parameters are shown in Table 1.

Table 1: Device parameters

Capacity	LBA	User Capacity(MB)
32GB	62533296	30,533
64GB	125045424	61,057
128GB	250069680	122,104
256GB	500118192	244,198
512GB	1000215216	488,386

2.2 Performance

Burst Transfer Rate: 16.0Gbps

Table 2: Performance

Capacity	32GB	64GB	128GB	256GB	512GB
Sequential* Read (max.)	450MB/s	890 MB/s	1300 MB/s	1300 MB/s	1200 MB/s
Sequential* Write (max.)	50 MB/s	100 MB/s	190 MB/s	340MB/s	480MB/s
4KB Random* Read (QD32)	18000	36000	47000	51000	51000
4KB Random* Write (QD32)	12000	22000	29000	47000	50000

Note: * Performance is based on CrystalDiskMark 5.1.2 with file size 1000MB of Queue Depth 32

2.3 Electrical Specifications

2.3.1 Power Requirement

Table 3: Innodisk M.2 (P80) 3ME2 Power Requirement

Item	Symbol	Rating	Unit
Input voltage	V_{IN}	+3.3 DC +- 5%	V

2.3.2 Power Consumption

Table 4: Power Consumption

Mode	Power Consumption (mA)
Read	845 (rms.)
Write	1130 (rms.)
Idle	380 (rms.)

* Target: 512GB M.2 (P80) 3ME2

2.4 Environmental Specifications

2.4.1 Temperature Ranges

Table 5: Temperature range for M.2 (P80) 3ME2

Temperature	Range
Operating	Standard Grade: 0°C to +70°C
	Industrial Grade:-40°C to +85°C
Storage	-55°C to +95°C

2.4.2 Humidity

Relative Humidity: 10-95%, non-condensing

2.4.3 Shock and Vibration

Table 6: Shock/Vibration Testing for M.2 (P80) 3ME2

Reliability	Test Conditions	Reference Standards
Vibration	7 Hz to 2K Hz, 20G, 3 axes	IEC 60068-2-6
Mechanical Shock	Duration: 0.5ms, 1500 G, 3 axes	IEC 60068-2-27

2.4.4 Mean Time between Failures (MTBF)

Table 7 summarizes the MTBF prediction results for various M.2 (P80) 3ME2 configurations. The analysis was performed using a RAM Commander™ failure rate prediction.

- **Failure Rate**: The total number of failures within an item population, divided by the total number of life units expended by that population, during a particular measurement interval under stated condition.
- **Mean Time between Failures (MTBF)**: A basic measure of reliability for repairable items: The mean number of life units during which all parts of the item perform within their specified limits, during a particular measurement interval under stated conditions.

Table 7: M.2 (P80) 3ME2 MTBF

Product	Condition	MTBF (Hours)
Innodisk M.2 (P80) 3ME2	Telcordia SR-332 GB, 25°C	>3,000,000

2.5 CE and FCC Compatibility

M.2 (P80) 3ME2 conforms to CE and FCC requirements.

2.6 RoHS Compliance

M.2 (P80) 3ME2 is fully compliant with RoHS directive.

2.7 Reliability

Table 8: M.2 (P80) 3ME2 TBW

Parameter	Value
Read Cycles	Unlimited Read Cycles
Flash endurance	3,000 P/E cycles
Wear-Leveling Algorithm	Support
Bad Blocks Management	Support
Error Correct Code	Support(LDPC)

TBW* (Total Bytes Written) Unit: TB

Capacity	Sequential workload	Client workload
32GB	93.6	38.7
64GB	187.2	77.40
128GB	374.4	135.49
256GB	748.8	202.85
512GB	1497.6	390

* Note:

1. Sequential: Mainly sequential write, tested by Vdbench.
2. Client: Follow JESD218 Test method and JESD219A Workload, tested by ULINK. (The capacity lower than 64GB client workload is not specified in JEDEC219A, the values are estimated.)
3. Based on out-of-box performance.

2.8 Transfer Mode

M.2 (P80) 3ME2 support following transfer mode:

PCIe Gen III 8Gbps

PCIe Gen II 4Gbps

PCIe Gen I 2Gbps

2.9 Pin Assignment

Innodisk M.2 (P80) 3ME2 follows standard M.2 spec, socket 2 key B-M PCIe-based SSD pinout. See Table 9 for M.2 (P80) 3ME2 pin assignment.

Table 9: Innodisk M.2 (P80) 3ME2 Pin Assignment

Signal Name	Pin #	Pin #	Signal Name
		75	GND
3.3V	74	73	GND
3.3V	72	71	GND
3.3V	70	69	NC
NC	68	67	NC
Notch	66	65	Notch
Notch	64	63	Notch
Notch	62	61	Notch
Notch	60	59	Notch
NC (Reserved)	58		
NC (Reserved)	56	57	GND
NC	54	55	REFCLKp
CLKREQ# (I/O)(0/3.3V)	52	53	REFCLKn
PERST# (I)(0/3.3V)	50	51	GND
NC	48	49	PERp0
NC	46	47	PERn0
NC	44	45	GND
SMB_DATA (I/O)(0/1.8V)	42	43	PETp0
SMB_CLK (I/O)(0/1.8V)	40	41	PETn0
NC	38	39	GND
NC	36	37	PERp1
NC	34	35	PERn1
NC	32	33	GND
NC	30	31	PETp1
NC	28	29	PETn1
NC	26	27	GND
NC	24	25	NC
NC	22	23	NC
NC	20	21	GND
Notch	18	19	Notch
Notch	16	17	Notch
Notch	14	15	Notch
Notch	12	13	Notch
NC	10	11	NC
NC	8	9	GND
NC	6	7	NC
3.3V	4	5	NC
3.3V	2	3	GND
		1	GND

2.10 Mechanical Dimensions

M.2 Type 2280-D2-B-M

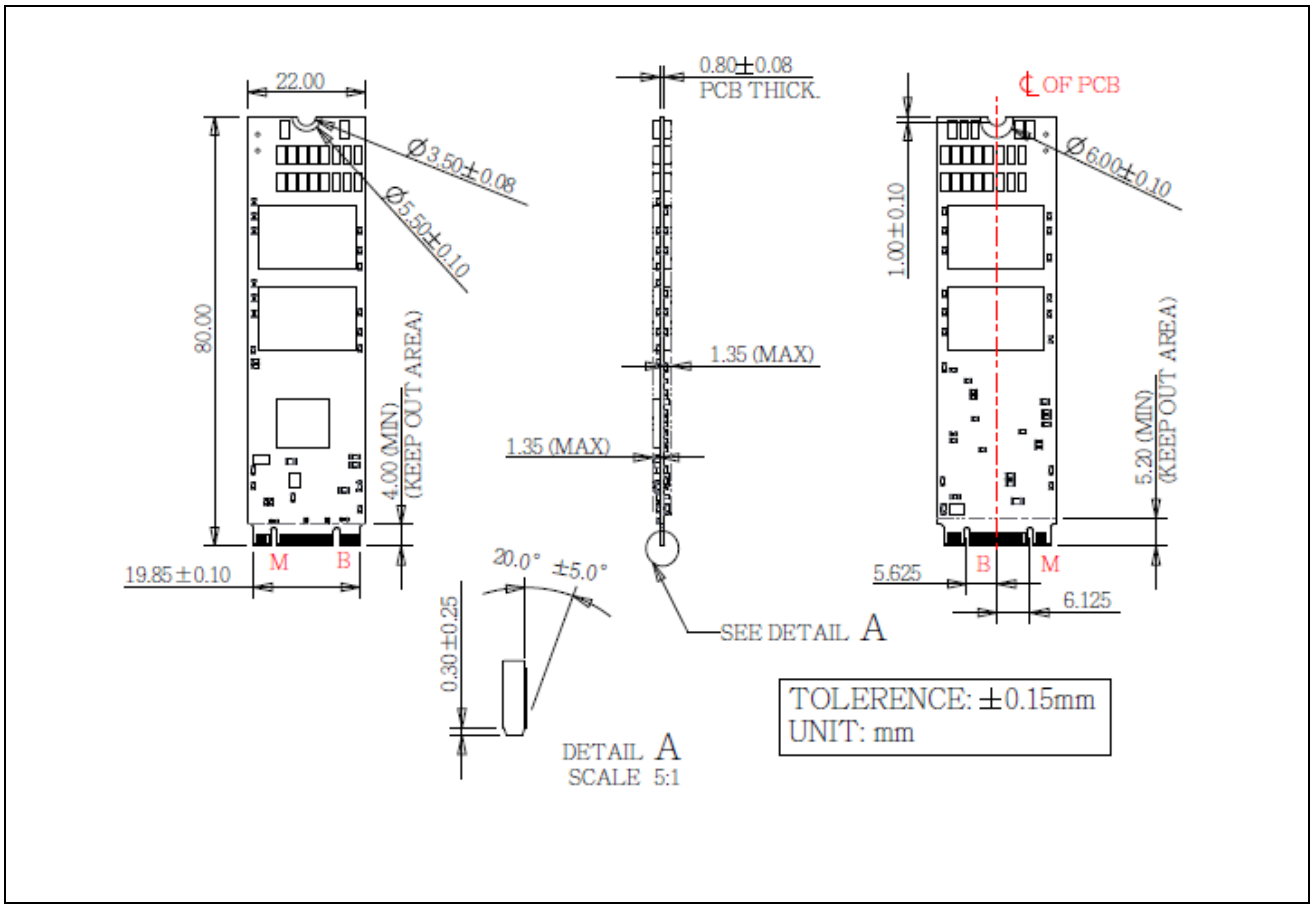


Figure 2: Innodisk M.2 (P80) 3ME2 diagram

***iCell is optional**

2.11 Assembly Weight

An Innodisk M.2 (P80) 3ME2 within NAND flash ICs, 64GB's weight is 7 grams approximately.

2.12 Seek Time

Innodisk M.2 (P80) 3ME2 is not a magnetic rotating design. There is no seek or rotational latency required.

2.13 NAND Flash Memory

Innodisk M.2 (P80) 3ME2 uses Multi Level Cell (MLC) NAND flash memory, which is non-volatility, high reliability and high speed memory storage.

3. Theory of Operation

3.1 Overview

Figure 2 shows the operation of Innodisk M.2 (P80) 3ME2 from the system level, including the major hardware blocks.

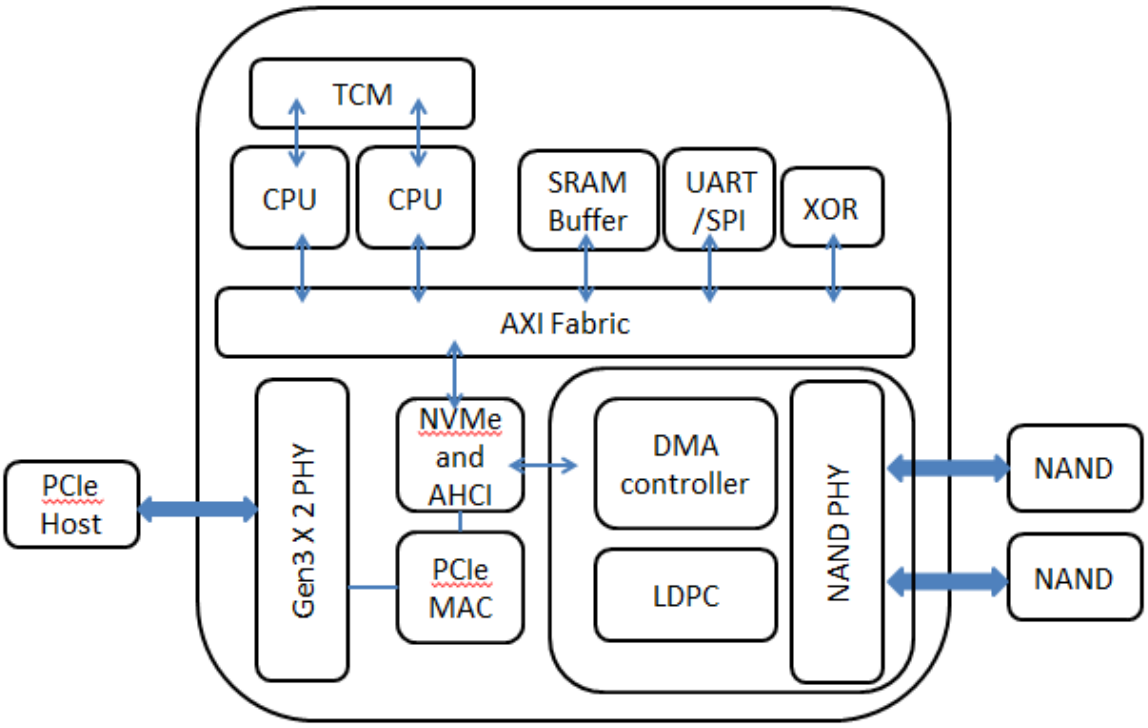


Figure 3: Innodisk M.2 (P80) 3ME2 Block Diagram

Innodisk M.2 (P80) 3ME2 integrates a PCIe Gen III x2 controller and NAND flash memories. Communication with the host occurs through the host interface, using the standard NVM protocol. Communication with the flash device(s) occurs through the flash interface.

3.2 PCIe Gen III x2 Controller

Innodisk M.2 (P80) 3ME2 is designed with 88NV1160, a PCIe Gen IIIx2 controller is compliant with NVMe 1.3, up to 16.0Gbps transfer speed. Also it is compliant with PCIe Gen 1, Gen 2 and Gen 3 specification. The controller supports up to 4 channels for flash interface.

3.3 Error Detection and Correction

Innodisk M.2 (P80) 3ME2 is designed with hardware LDPC ECC engine with hard-decision and soft-decision decoding. Low-density parity-check (LDPC) codes have excellent error correcting performance close to the Shannon limit when decoded with the belief-propagation (BP) algorithm using soft-decision information.

3.4 Wear-Leveling

Flash memory can be erased within a limited number of times. This number is called the ***erase cycle limit*** or ***write endurance limit*** and is defined by the flash array vendor. The erase cycle limit applies to each individual erase block in the flash device.

Innodisk M.2 (P80) 3ME2 uses a combination of two types of wear leveling- dynamic and static wear leveling- to distribute write cycling across an SSD and balance erase count of each block, thereby extending flash lifetime.

3.5 Bad Blocks Management

Bad Blocks are blocks that contain one or more invalid bits whose reliability are not guaranteed. The Bad Blocks may be presented while the SSD is shipped, or may develop during the life time of the SSD. When the Bad Blocks is detected, it will be flagged, and not be used anymore. The SSD implement Bad Blocks management, Bad Blocks replacement, Error Correct Code to avoid data error occurred. The functions will be enabled automatically to transfer data from Bad Blocks to spare blocks, and correct error bit.

3.6 Power Cycling

Innodisk's power cycling management is a comprehensive data protection mechanism that functions before and after a sudden power outage to SSD. Low-power detection terminates data writing before an abnormal power-off, while table-remapping after power-on deletes corrupt data and maintains data integrity. Innodisk's power cycling provides effective power cycling management, preventing data stored in flash from degrading with use.

3.7 Garbage Collection

Garbage collection is used to maintain data consistency and perform continual data cleansing on SSDs. It runs as a background process, freeing up valuable controller resources while sorting good data into available blocks, and deleting bad blocks. It also significantly reduces write operations to the drive, thereby increasing the SSD's speed and lifespan.

3.8 End to End Data Path Protection

End-to-end Data Path Protection that secures the data transmission between host system and NAND Flash. In the transmission path, no matter in or out, all buffer and storage implement Error Code Correction that optimizes the data integrity in the whole transmission of SSD.

3.9 Thermal Management

M.2 (P80) 3ME2 has build-in thermal sensor which can detect environment temperature of SSD. In the meantime, firmware will monitor the thermal sensor to prevent any failure of overheating. During extreme temperature, firmware will adjust the data transfer behavior to maintain the SSD's reliable operation.

4. Installation Requirements

4.1 M.2 (P80) 3ME2 Pin Directions

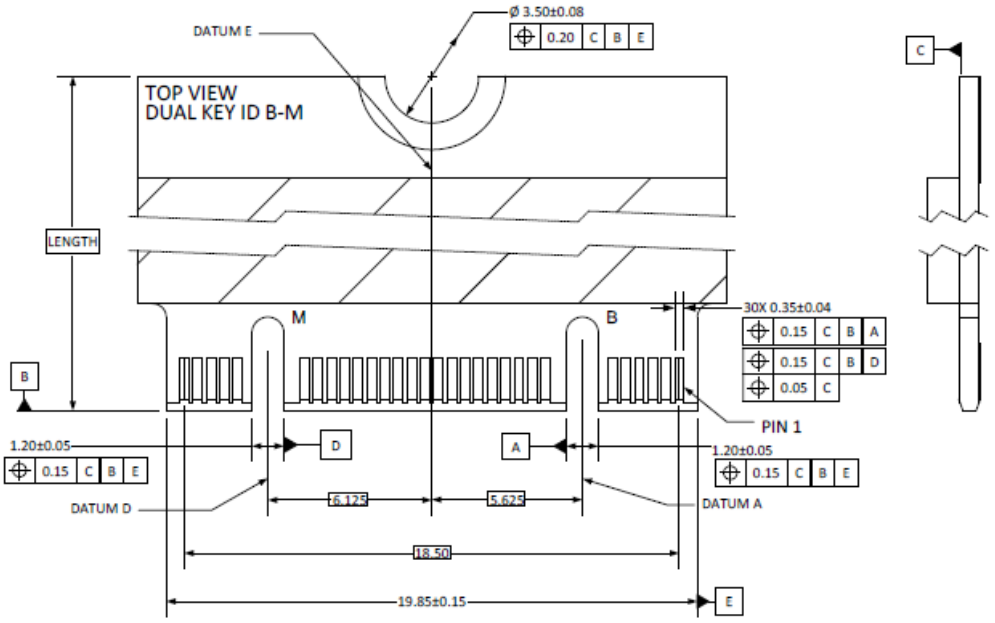


Figure 4: Signal Segment and Power Segment

4.2 Electrical Connections for M.2 (P80) 3ME2

M.2 interconnect is based on a 75 position Edge Card connector. The 75 position connector is intended to be keyed so as to distinguish between families of host interfaces and the various Sockets used in general Platforms. M.2(P80) 3ME2 is compliant with M.2 Socket 2 key B-M.

4.3 Device Drive

M.2(P42) 3ME2 is compliant with NVMe 1.3. Both Operation System and BIOS should include NVMe driver to compatible with NVMe device. Nowadays, most of OS includes NVMe in-box driver now. For more information about the driver support in each OS, please visit the website http://nvmexpress.org/resources/drivers. For BIOS NVMe driver support please contact with motherboard manufacturers.

5. SMART / Health Information

This log page is used to provide SMART and general health information. The information provided is over the life of the controller and is retained across power cycles. More details about Set Features command; please refer to NVM Express 1.3

5.1 Get Log Page(Log Identifier 02h)

Innodisk 3ME2 series SMART / Health Information Log are listed in following table.

Table 10: Get Log Page – SMART / Health Information Log

<table>
<tr><th>Bytes</th><th>Description</th></tr>
<tr><td>0</td><td>Critical Warning: This field indicates critical warnings for the state of the controller. Each bit corresponds to a critical warning type; multiple bits may be set. If a bit is cleared to ‘0’, then that critical warning does not apply. Critical warnings may result in an asynchronous event notification to the host. Bits in this field represent the current associated state and are not persistent.
<table>
<tr><th>Bit</th><th>Definition</th></tr>
<tr><td>00</td><td>If set to ‘1’, then the available spare space has fallen below the threshold.</td></tr>
<tr><td>01</td><td>If set to ‘1’, then a temperature is above an over temperature threshold or below an under</td></tr>
<tr><td>02</td><td>If set to ‘1’, then the NVM subsystem reliability has been degraded due to significant media related</td></tr>
<tr><td>03</td><td>If set to ‘1’, then the media has been placed in read only mode.</td></tr>
<tr><td>04</td><td>If set to ‘1’, then the volatile memory backup device has failed. This field is only valid if the</td></tr>
<tr><td>07:05</td><td>Reserved</td></tr>
</table></td></tr>
<tr><td>2:1</td><td>Composite Temperature: Contains a value corresponding to a temperature in degrees Kelvin that represents the current composite temperature of the controller and namespace(s) associated with that controller. The manner in which this value is computed is implementation specific and may not represent the actual temperature of any physical point in the NVM subsystem. The value of this field may be used to trigger an asynchronous event.</td></tr>
</table>

	Warning and critical overheating composite temperature threshold values are reported by the WCTEMP and CCTEMP fields in the Identify Controller data structure.
3	**Available Spare:** Contains a normalized percentage (0 to 100%) of the remaining spare capacity available.
4	**Available Spare Threshold:** When the Available Spare falls below the threshold indicated in this field, an asynchronous event completion may occur. The value is indicated as a normalized percentage (0 to 100%).
5	**Percentage Used:** Contains a vendor specific estimate of the percentage of NVM subsystem life used based on the actual usage and the manufacturer's prediction of NVM life. A value of 100 indicates that the estimated endurance of the NVM in the NVM subsystem has been consumed, but may not indicate an NVM subsystem failure. The value is allowed to exceed 100. Percentages greater than 254 shall be represented as 255. This value shall be updated once per power-on hour (when the controller is not in a sleep state). Refer to the JEDEC JESD218A standard for SSD device life and endurance measurement techniques.
31:6	**Reserved**
47:32	**Data Units Read:** Contains the number of 512 byte data units the host has read from the controller; this value does not include metadata. This value is reported in thousands (i.e., a value of 1 corresponds to 1000 units of 512 bytes read) and is rounded up. When the LBA size is a value other than 512 bytes, the controller shall convert the amount of data read to 512 byte units. For the NVM command set, logical blocks read as part of Compare and Read operations shall be included in this value.
63:48	**Data Units Written:** Contains the number of 512 byte data units the host has written to the controller; this value does not include metadata. This value is reported in thousands (i.e., a value of 1 corresponds to 1000 units of 512 bytes written) and is rounded up. When the LBA size is a value other than 512 bytes, the controller shall convert the amount of data written to 512 byte units. For the NVM command set, logical blocks written as part of Write operations shall be included in this value. Write Uncorrectable commands shall not impact this value.
79:64	**Host Read Commands:** Contains the number of read commands completed by the controller. For the NVM command set, this is the number of Compare and Read commands.

95:80	**Host Write Commands:** Contains the number of write commands completed by the controller. For the NVM command set, this is the number of Write commands.
111:96	**Controller Busy Time:** Contains the amount of time the controller is busy with I/O commands. The controller is busy when there is a command outstanding to an I/O Queue (specifically, a command was issued via an I/O Submission Queue Tail doorbell write and the corresponding completion queue entry has not been posted yet to the associated I/O Completion Queue). This value is reported in minutes.
127:112	**Power Cycles:** Contains the number of power cycles.
143:128	**Power On Hours:** Contains the number of power-on hours. This may not include time that the controller was powered and in a non-operational power state.
159:144	**Unsafe Shutdowns:** Contains the number of unsafe shutdowns. This count is incremented when a shutdown notification (CC.SHN) is not received prior to loss of power.
175:160	**Media and Data Integrity Errors:** Contains the number of occurrences where the controller detected an unrecovered data integrity error. Errors such as uncorrectable ECC, CRC checksum failure, or LBA tag mismatch are included in this field.
191:176	**Number of Error Information Log Entries:** Contains the number of Error Information log entries over the life of the controller.
195:192	**Warning Composite Temperature Time:** Contains the amount of time in minutes that the controller is operational and the Composite Temperature is greater than or equal to the Warning Composite Temperature Threshold (WCTEMP) field and less than the Critical Composite Temperature Threshold (CCTEMP) field in the Identify Controller data structure. If the value of the WCTEMP or CCTEMP field is 0h, then this field is always cleared to 0h regardless of the Composite Temperature value.
199:196	**Critical Composite Temperature Time:** Contains the amount of time in minutes that the controller is operational and the Composite Temperature is greater than the Critical Composite Temperature Threshold (CCTEMP) field in the Identify Controller data structure. If the value of the CCTEMP field is 0h, then this field is always cleared to 0h regardless of the Composite Temperature value.
201:200	**Temperature Sensor 1:** Contains the current temperature reported by temperature sensor 1.
203:202	**Temperature Sensor 2:** Contains the current temperature reported by temperature sensor 2.
205:204	**Temperature Sensor 3:** Contains the current temperature reported by temperature sensor 3.

207:206	**Temperature Sensor 4:** Contains the current temperature reported by temperature sensor 4.
209:208	**Temperature Sensor 5:** Contains the current temperature reported by temperature sensor 5.
211:210	**Temperature Sensor 6:** Contains the current temperature reported by temperature sensor 6.
213:212	**Temperature Sensor 7:** Contains the current temperature reported by temperature sensor 7.
215:214	**Temperature Sensor 8:** Contains the current temperature reported by temperature sensor 8.
511:216	**Reserved**

6. Part Number Rule

CODE	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21
	D	**E**	**M**	**2**	**8**	**-**	**6**	**4**	**G**	**M**	**6**	**1**	**B**	**C**	**A**	**Q**	**C**	**(P)**	**-**	**X**	**X**

Definition		
Code 1st (Disk)		**Code 14th (Operation Temperature)**
D : Disk		C: Standard Grade (0℃~ +70℃)
Code 2nd (Feature set)		W: Industrial Grade (-40℃~ +85℃)
E : Embedded series		
Code 3rd ~5th (Form factor)		**Code 15th (Internal control)**
M28: M.2 Type 2280-D2-B-M		A~Z: BGA PCB version.
Code 7th ~9th (Capacity)		**Code 16th (Channel of data transfer)**
32G: 32GB	64G: 64GB	A28: 128GB	D: Dual Channels
B56:256GB	C12:512GB		Q: Quad Channels
Code 10th ~12th (Controller)		**Code 17th (Flash Type)**
M61: Marvell 88NV1160		C: Toshiba MLC
Code 13th (Flash mode)		**Code 18th(iCell)**
B: Synchronous NAND for Toshiba 15nm		P: optional function reserved for iCell
		Code 19th ~21st (Customize code)

7. Appendix

REACH

innodisk

宜鼎國際股份有限公司
Innodisk Corporation

Tel:(02)7703-3000 Fax:(02) 7703-3555 Internet: http://www.innodisk.com/

REACH Declaration of Conformity

Manufacturer Product: All Innodisk EM Flash and Dram products

1. 宜鼎國際股份有限公司（以下稱本公司）特此保證此售予貴公司之產品，皆符合歐盟化學品法案(Registration , Evaluation and Authorization of Chemicals : (EC) No 1907/2006 REACH)以及附錄 XIV 中的限用物質之規定 (http://www.echa.europa.eu/de/candidate-list-table **last updated: 12/01/2017，SVHC's 173)**。
所提供之產品包含：(1) 產品或產品所使用到的所有原物料；(2)包裝材料；(3)設計、生產及重工過程中所使用到的所有原物料。
We Innodisk Corporation hereby declare that our products are in compliance with the requirements according to the (EC) No 1907/2006 REACH Regulation and restricted substances in Annex XIV (http://www.echa.europa.eu/de/candidate-list-table **last updated: 12/01/2017，SVHC's 173).**
Products include： 1) Product and raw material used by the product ; 2) Packaging material ; 3) Raw material used in the process of design, production and rework.
2. 本公司同意因本保證書或與本保證書相關事宜有所爭議時，雙方宜友好協商，達成協議。
InnoDisk Corporation agrees that both parties shall settle any dispute arising from or in connection with this Declaration of Conformity by friendly negotiations.

立 保 證 書 人 (Guarantor)

Company name 公司名稱： InnoDisk Corporation 宜鼎國際股份有限公司

Company Representative 公司代表人： Randy Chien 簡川勝

Company Representative Title 公司代表人職稱： Chairman 董事長

Date 日期： 2017 / 02 / 08

RoHS

innodisk

宜鼎國際股份有限公司
Innodisk Corporation

Tel:(02)7703-3000 Fax:(02) 7703-3555 Internet: http://www.innodisk.com/

RoHS 自我宣告書(RoHS Declaration of Conformity)

Manufacturer Product: All Innodisk EM Flash and Dram products

一、 宜鼎國際股份有限公司（以下稱本公司）特此保證售予貴公司之所有產品，皆符合歐盟 2011/65/EU 及(EU) 2015/863 關於 RoHS 之規範要求。

Innodisk Corporation declares that all products sold to the company, are complied with European Union RoHS Directive (2011/65/EU) and (EU) 2015/863 requirement.

二、 本公司同意因本保證書或與本保證書相關事宜有所爭議時，雙方宜友好協商，達成協議。

Innodisk Corporation agrees that both parties shall settle any dispute arising from or in connection with this Declaration of Conformity by friendly negotiations.

Name of hazardous substance	Limited of RoHS ppm (mg/kg)
鉛 (Pb)	< 1000 ppm
汞 (Hg)	< 1000 ppm
鎘 (Cd)	< 100 ppm
六價鉻 (Cr 6+)	< 1000 ppm
多溴聯苯 (PBBs)	< 1000 ppm
多溴二苯醚 (PBDEs)	< 1000 ppm
鄰苯二甲酸二(2-乙基己基)酯 (DEHP)	< 1000 ppm
鄰苯二甲酸丁酯苯甲酯 (BBP)	< 1000 ppm
鄰苯二甲酸二丁酯 (DBP)	< 1000 ppm
鄰苯二甲酸二異丁酯 (DIBP)	< 1000 ppm

立 保 證 書 人 (Guarantor)

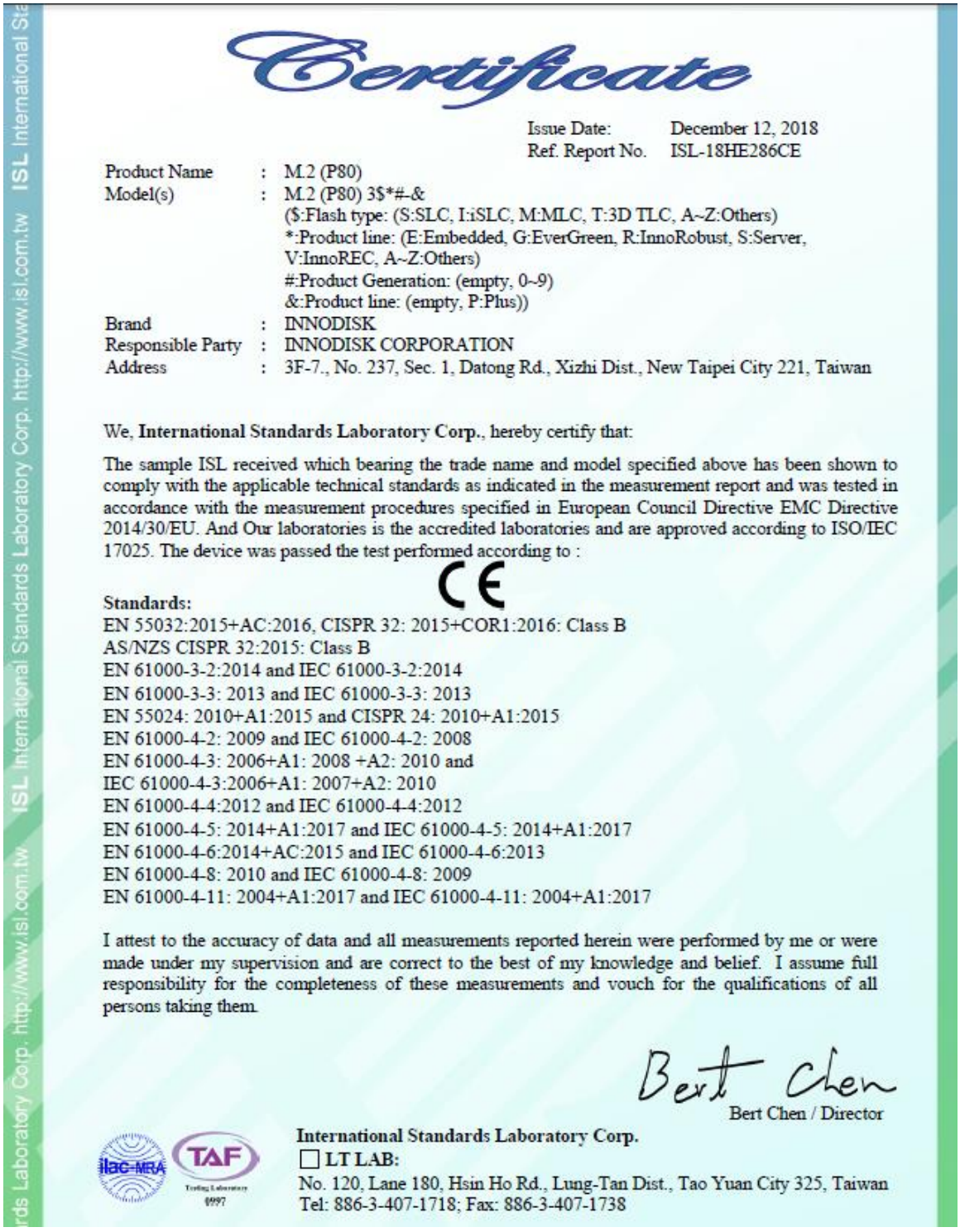
Company name 公司名稱： Innodisk Corporation 宜鼎國際股份有限公司

Company Representative 公司代表人： Randy Chien 簡川勝

Company Representative Title 公司代表人職稱： Chairman 董事長

Date 日期： 2017 / 01 / 18

CE



Certificate

Issue Date: December 12, 2018
Ref. Report No. ISL-18HE286CE

Product Name	:	M.2 (P80)
Model(s)	:	M.2 (P80) 3$*#-& ($:Flash type: (S:SLC, I:iSLC, M:MLC, T:3D TLC, A~Z:Others) *:Product line: (E:Embedded, G:EverGreen, R:InnoRobust, S:Server, V:InnoREC, A~Z:Others) #:Product Generation: (empty, 0~9) &:Product line: (empty, P:Plus))
Brand	:	INNODISK
Responsible Party	:	INNODISK CORPORATION
Address	:	3F-7., No. 237, Sec. 1, Datong Rd., Xizhi Dist., New Taipei City 221, Taiwan

We, **International Standards Laboratory Corp.**, hereby certify that:

The sample ISL received which bearing the trade name and model specified above has been shown to comply with the applicable technical standards as indicated in the measurement report and was tested in accordance with the measurement procedures specified in European Council Directive EMC Directive 2014/30/EU. And Our laboratories is the accredited laboratories and are approved according to ISO/IEC 17025. The device was passed the test performed according to :

CE

Standards:
EN 55032:2015+AC:2016, CISPR 32: 2015+COR1:2016: Class B
AS/NZS CISPR 32:2015: Class B
EN 61000-3-2:2014 and IEC 61000-3-2:2014
EN 61000-3-3: 2013 and IEC 61000-3-3: 2013
EN 55024: 2010+A1:2015 and CISPR 24: 2010+A1:2015
EN 61000-4-2: 2009 and IEC 61000-4-2: 2008
EN 61000-4-3: 2006+A1: 2008 +A2: 2010 and
IEC 61000-4-3:2006+A1: 2007+A2: 2010
EN 61000-4-4:2012 and IEC 61000-4-4:2012
EN 61000-4-5: 2014+A1:2017 and IEC 61000-4-5: 2014+A1:2017
EN 61000-4-6:2014+AC:2015 and IEC 61000-4-6:2013
EN 61000-4-8: 2010 and IEC 61000-4-8: 2009
EN 61000-4-11: 2004+A1:2017 and IEC 61000-4-11: 2004+A1:2017

I attest to the accuracy of data and all measurements reported herein were performed by me or were made under my supervision and are correct to the best of my knowledge and belief. I assume full responsibility for the completeness of these measurements and vouch for the qualifications of all persons taking them.

Bert Chen

Bert Chen / Director

International Standards Laboratory Corp.
☐ **LT LAB:**
No. 120, Lane 180, Hsin Ho Rd., Lung-Tan Dist., Tao Yuan City 325, Taiwan
Tel: 886-3-407-1718; Fax: 886-3-407-1738

FCC

ISL International Standards Laboratory Corp. http://www.isl.com.tw

Certificate

Issue Date: December 12, 2018
Ref. Report No. ISL-18HE286FB

Product Name	:	M.2 (P80)
Model(s)	:	M.2 (P80) 3$*#-& ($:Flash type: (S:SLC, I:iSLC, M:MLC, T:3D TLC, A~Z:Others) *:Product line: (E:Embedded, G:EverGreen, R:InnoRobust, S:Server, V:InnoREC, A~Z:Others) #:Product Generation: (empty, 0~9) &:Product line: (empty, P:Plus))
Brand	:	INNODISK
Applicant	:	INNODISK CORPORATION
Address	:	3F-7., No. 237, Sec. 1, Datong Rd., Xizhi Dist., New Taipei City 221, Taiwan

We, **International Standards Laboratory Corp.**, hereby certify that:

The sample ISL received which bearing the trade name and model specified above has shown to comply with the applicable technical standards as indicated in the measurement report and was tested in accordance with the measurement procedures specified. (refer to Test Report if any modifications were made for compliance). And Our laboratories is the accredited laboratories and are approved according to ISO/IEC 17025.

Standards:

FCC CFR Title 47 Part 15 Subpart B: Section 15.107 and 15.109
ANSI C63.4-2014
Industry Canada Interference-Causing Equipment Standard ICES-003 Issue 6: 2016
Class B

I attest to the accuracy of data and all measurements reported herein were performed by me or were made under my supervision and are correct to the best of my knowledge and belief. I assume full responsibility for the completeness of these measurements and vouch for the qualifications of all persons taking them.

Bert Chen

Bert Chen / Director

International Standards Laboratory Corp.
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